



Parameter	Rating	Units
Blocking Voltage	350	V <sub>P</sub>
Load Current	100	mA
Max On-Resistance	35	Ω

**Features**

- 3750V<sub>rms</sub> Input/Output Isolation
- Bidirectional Current Sensing
- Bidirectional Current Switching
- Replaces up to Three or Four Components
- Three Functions in One Package
- Small 16-Pin SOIC Package (PCMCIA Compatible)
- FCC Compatible
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Tape & Reel Versions Available

**Applications**

- Telecommunications
  - Telecom Switching
  - Tip/Ring Circuits
  - Modem Switching (Laptop, Notebook, Pocket Size)
  - Hook Switch
  - Dial Pulsing
  - Ground Start
  - Ringing Injection
- Instrumentation
  - Multiplexers
  - Data Acquisition
  - Electronic Switching
  - I/O Subsystems
  - Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

**Description**

The IAD110P Multifunction Telecom switch combines a 350V normally open (1-Form-A) relay and two optocouplers in a single package. The relay uses optically coupled MOSFET technology to provide 3750V<sub>rms</sub> of input to output isolation. The efficient MOSFET switch and photovoltaic die use Clare's patented OptoMOS® architecture. The optically coupled output is controlled by highly efficient GaAIAs infrared LEDs. The IAD110P enables telecom circuit designers to combine three discrete functions in a single component that uses less space than traditional discrete component solutions.

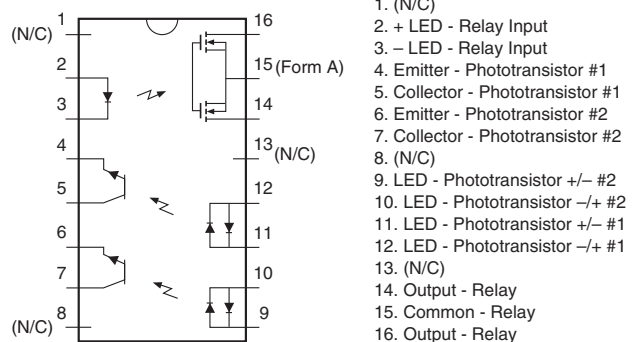
**Approvals**

- UL Recognized Component: File E76270
- CSA Certified Component: Certificate 1305490
- EN/IEC 60950-1 Certified Component:  
TUV Certificate: B 09 07 49410 006

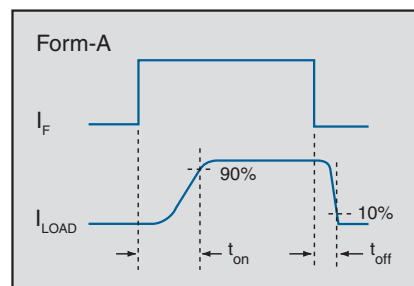
**Ordering Information**

Part #	Description
IAD110P	16-Pin SOIC (50/Tube)
IAD110PTR	16-Pin SOIC (1000/Reel)

**Pin Configuration**



**Switching Characteristics of Normally Open Devices**



**Absolute Maximum Ratings @ 25°C**

Parameter	Ratings	Units
Input Control Current, Relay	50	mA
Total Package Dissipation <sup>1</sup>	1	W
Isolation Voltage, Input to Output	3750	V <sub>rms</sub>
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

<sup>1</sup> Derate linearly 1.67 mW / °C

*Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.*

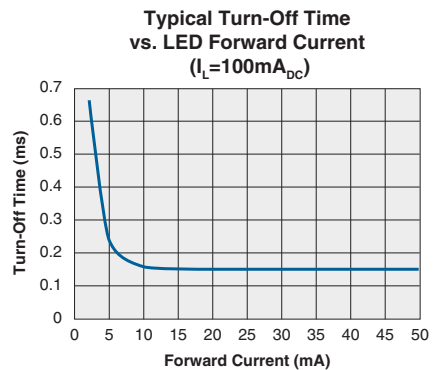
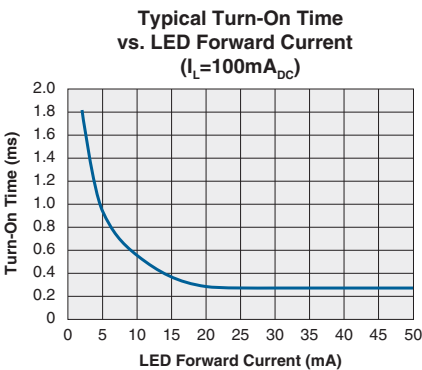
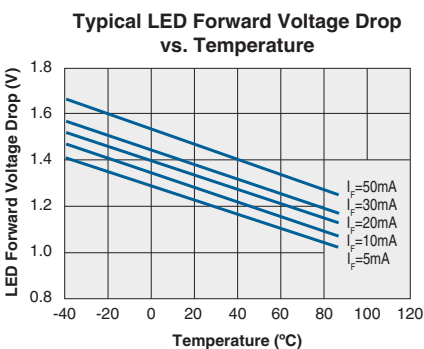
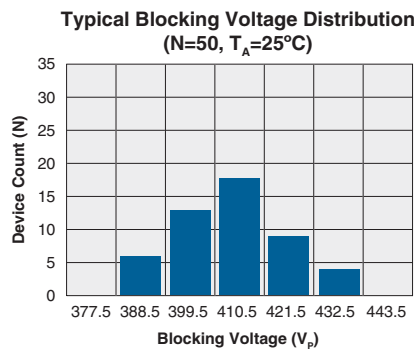
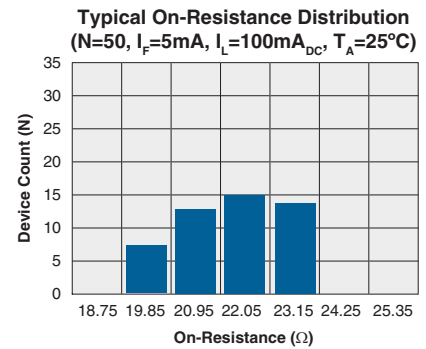
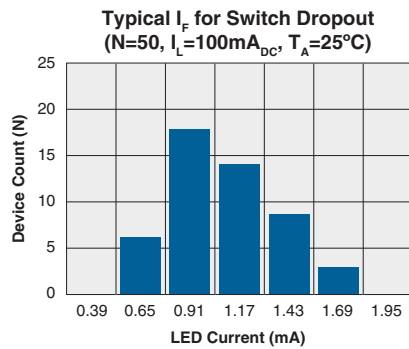
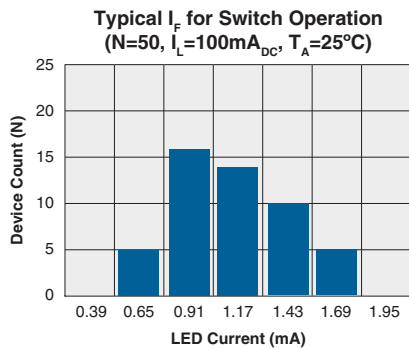
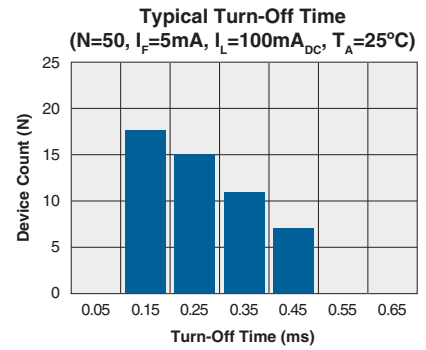
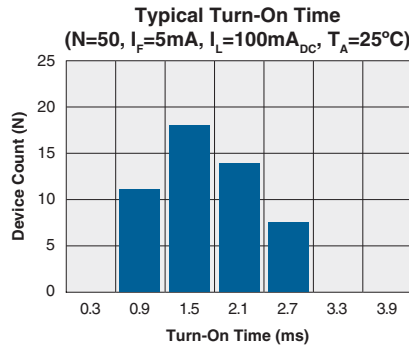
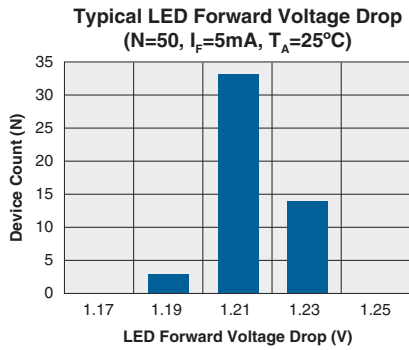
**Electrical Characteristics @25°C: Relay Section**

Parameter	Conditions	Symbol	Min	Typ	Max	Units
<b>Output Characteristics</b>						
Blocking Voltage (Peak)	I <sub>L</sub> =1μA	V <sub>L</sub>	-	-	350	V <sub>p</sub>
Load Current						
Continuous	-	I <sub>L</sub>	-	-	100	mA
Peak	t=10ms	I <sub>LPK</sub>	-	-	350	mA
On-Resistance	I <sub>L</sub> =100mA	R <sub>ON</sub>	-	-	35	Ω
Off-State Leakage Current	V <sub>L</sub> =350V, T <sub>J</sub> =25°C	I <sub>LEAK</sub>	-	-	1	μA
<b>Switching Speeds</b>						
Turn-On	I <sub>F</sub> =5mA, V <sub>L</sub> =10V	t <sub>on</sub>	-	-	3	ms
Turn-Off		t <sub>off</sub>	-	-	3	ms
Output Capacitance	V <sub>L</sub> =50V, f=1MHz	C <sub>OUT</sub>	-	25	-	pF
<b>Input Characteristics</b>						
Input Control Current	I <sub>L</sub> =100mA	I <sub>F</sub>	-	-	5	mA
Input Dropout Current	I <sub>L</sub> =1mA	I <sub>F</sub>	0.4	-	-	mA
Input Voltage Drop	I <sub>F</sub> =5mA	V <sub>F</sub>	0.9	1.2	1.4	V
Reverse Input Voltage	-	V <sub>R</sub>	-	-	5	V
Reverse Input Current	V <sub>R</sub> =5V	I <sub>R</sub>	-	-	10	μA

**Electrical Characteristics @25°C: Detector Section**

Parameter	Conditions	Symbol	Min	Typ	Max	Units
<b>Output Characteristics</b>						
Phototransistor Blocking Voltage	I <sub>C</sub> =10μA	BV <sub>CEO</sub>	20	50	-	V
Phototransistor Dark Current	V <sub>CE</sub> =5V, I <sub>F</sub> =0mA	I <sub>CEO</sub>	-	50	500	nA
Saturation Voltage	I <sub>C</sub> =2mA, I <sub>F</sub> =16mA	V <sub>SAT</sub>	-	0.3	0.5	V
Current Transfer Ratio	I <sub>F</sub> =6mA, V <sub>CE</sub> =0.5V	CTR	33	-	-	%
<b>Input Characteristics</b>						
Input Control Current	I <sub>C</sub> =2mA, V <sub>CE</sub> =0.5V	I <sub>F</sub>	-	2	6	mA
Input Voltage Drop	I <sub>F</sub> =5mA	V <sub>F</sub>	0.9	1.2	1.4	V
Input Current (Detector Must be Off)	I <sub>C</sub> =1μA, V <sub>CE</sub> =5V	-	5	25	-	μA
Capacitance, Input to Output	V <sub>L</sub> =50V, f=1MHz	C <sub>IO</sub>	-	3	-	pF
Isolation, Input to Output	-	V <sub>IO</sub>	3750	-	-	V <sub>rms</sub>

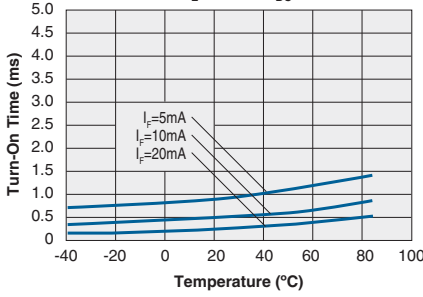
**RELAY PERFORMANCE DATA \***



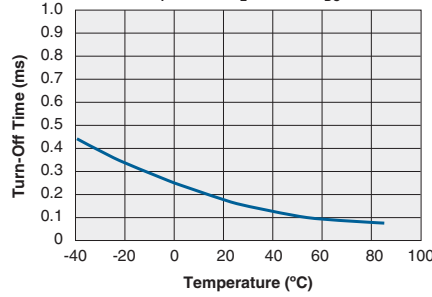
\* The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

RELAY PERFORMANCE DATA (cont.)\*

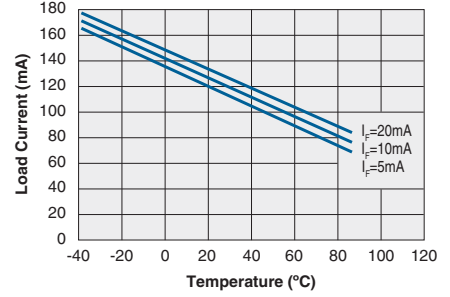
Typical Turn-On Time vs. Temperature  
( $I_L=100\text{mA}_{DC}$ )



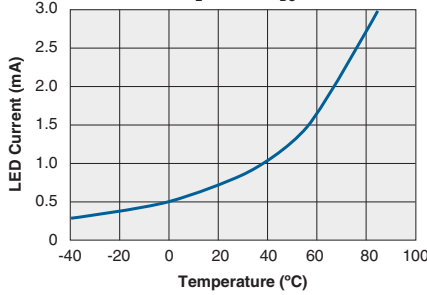
Typical Turn-Off vs. Temperature  
( $I_F=5\text{mA}$ ,  $I_L=100\text{mA}_{DC}$ )



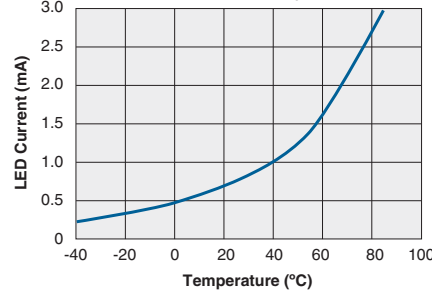
Typical Load Current vs. Temperature



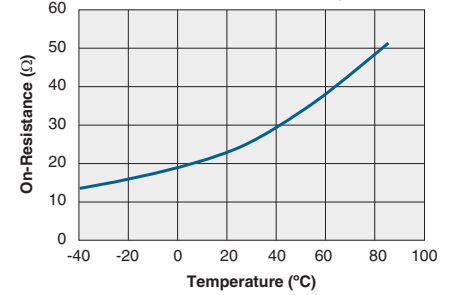
Typical  $I_F$  for Switch Operation vs. Temperature  
( $I_L=100\text{mA}_{DC}$ )



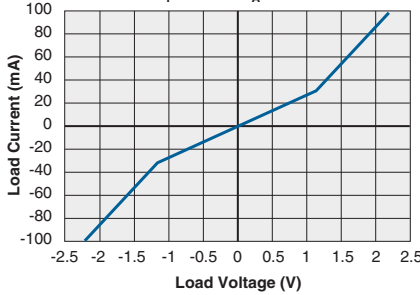
Typical  $I_F$  for Switch Dropout vs. Temperature  
( $I_L=100\text{mA}_{DC}$ )



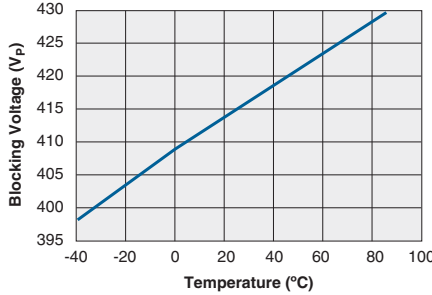
Typical On-Resistance vs. Temperature  
( $I_F=5\text{mA}$ ,  $I_L=100\text{mA}_{DC}$ )



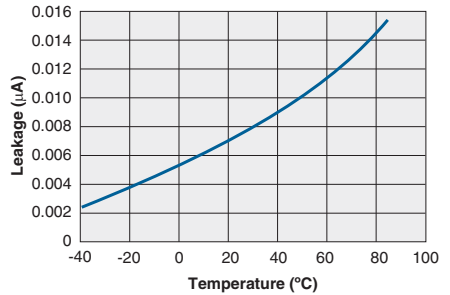
Typical Load Current vs. Load Voltage  
( $I_F=5\text{mA}$ ,  $T_A=25^\circ\text{C}$ )



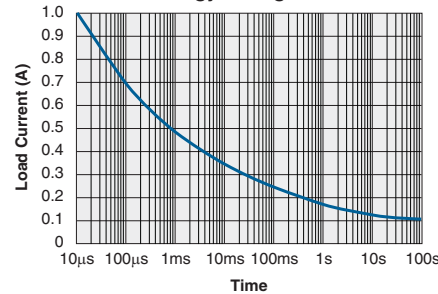
Typical Blocking Voltage vs. Temperature



Typical Leakage vs. Temperature Measured across Pins 14&16



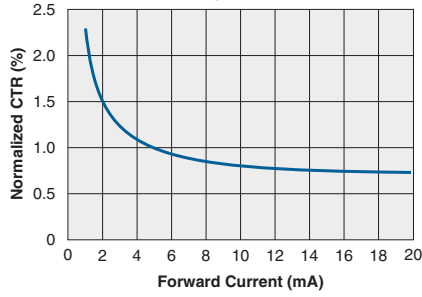
Energy Rating Curve



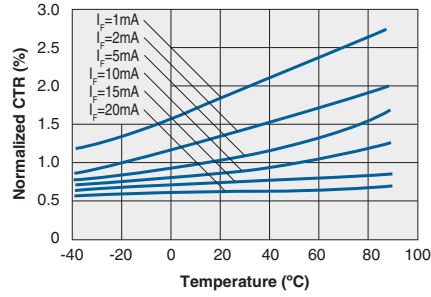
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**DETECTOR PERFORMANCE DATA\***

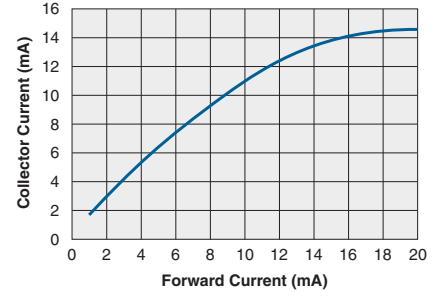
**Typical Normalized CTR vs. Forward Current**  
( $V_{CE}=0.8V$ )



**Typical Normalized CTR vs. Temperature**  
( $V_{CE}=0.8V$ )



**Typical Collector Current vs. Forward Current**  
( $V_{CE}=0.8V$ )



\* The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

**Manufacturing Information**

**Moisture Sensitivity**



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Clare classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
IAD110P	MSL 1

**ESD Sensitivity**



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

**Reflow Profile**

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
IAD110P	260°C for 30 seconds

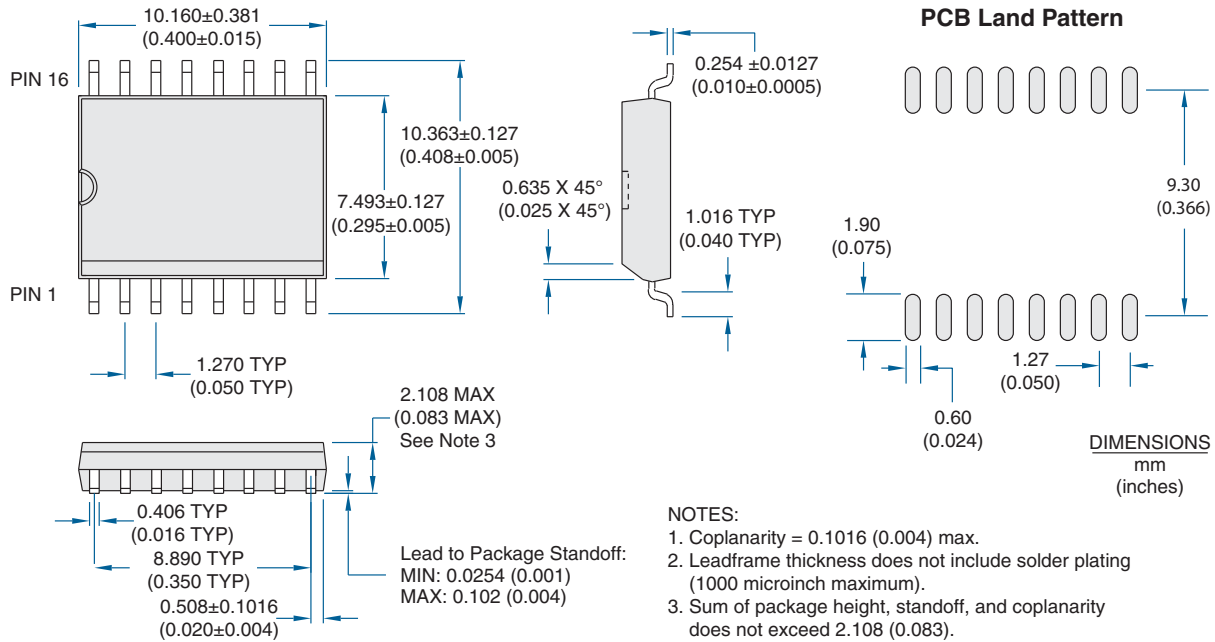
**Board Wash**

Clare recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since Clare employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

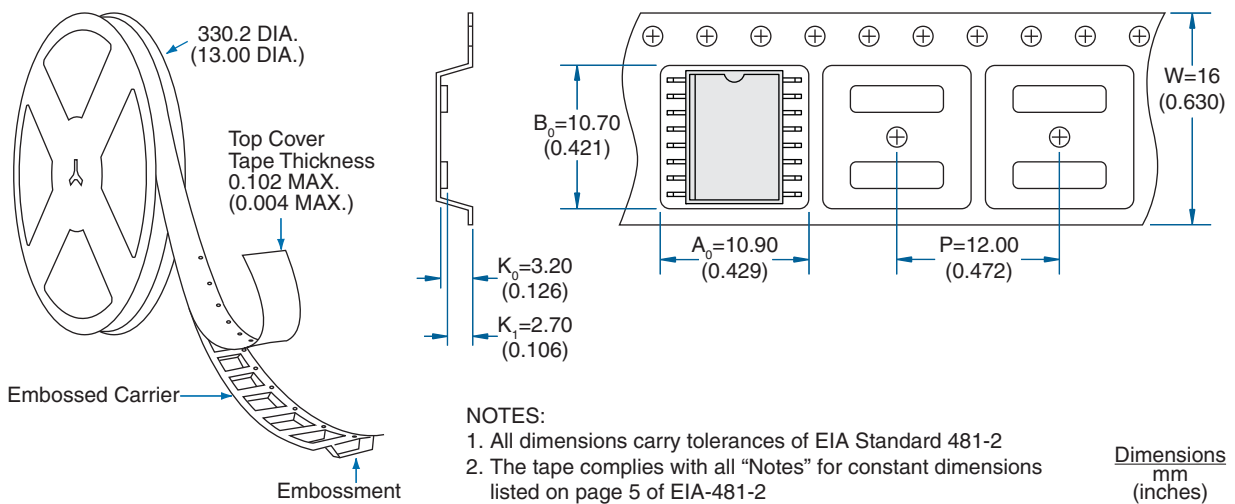


### MECHANICAL DIMENSIONS

#### IAD110P



#### IAD110P Tape & Reel



For additional information please visit our website at: [www.clare.com](http://www.clare.com)

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